

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-MOS FET

TLP200D

PBX

MODEM · FAX CARD

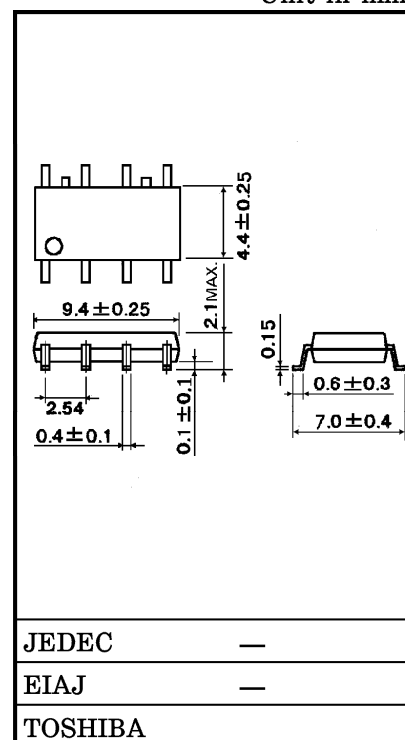
MEASUREMENT INSTRUMENT

Unit in mm

The TOSHIBA TLP200D consists of gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a 8 pin SOP.

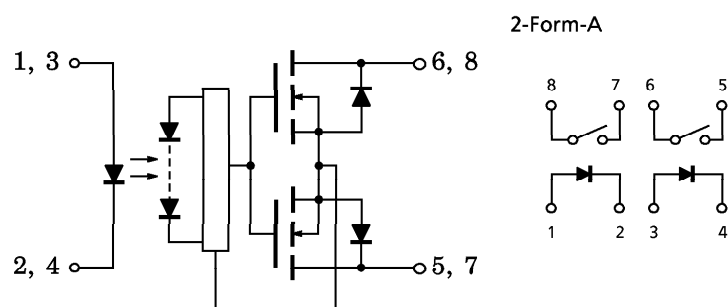
The TLP200D is a 2-Form-A switch which is suitable for replacement of mechanical relays in many applications which require space savings.

- SOP 8 pin (2.54SOP8) : 2-Form-A
- Peak Off-State Voltage : 200 V (MIN.)
- Trigger LED Current : 3 mA (MAX.)
- On-State Current : 150 mA (MAX.)
- On-State Resistance : $8\ \Omega$ (MAX.)
- Isolation Voltage : 1500 V_{rms} (MIN.)
- UL Recognized : UL1577, File No. E67349

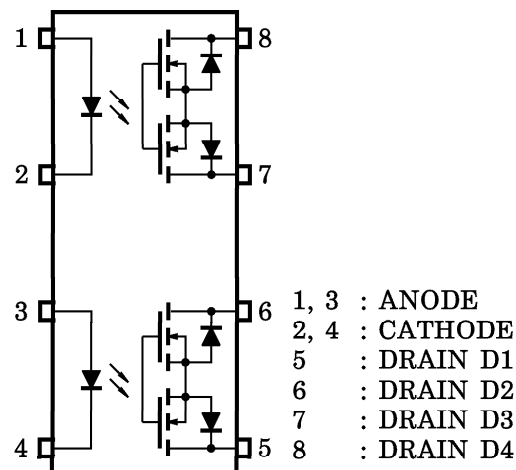


Weight : 0.2 g

SCHEMATIC



PIN CONFIGURATION (TOP VIEW)



980910EBC2

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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	I_F	50	mA
	Forward Current Derating (Ta $\geq$ 25°C)	$\Delta I_F / ^\circ\text{C}$	-0.5	mA / °C
	Pulse Forward Current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse Voltage	V_R	5	V
	Junction Temperature	T_j	125	°C
DETECTOR	Off-State Output Terminal Voltage	V_{OFF}	200	V
	On-State Current	I_{ON}	150	mA
	On-State RMS Current Derating (Ta $\geq$ 25°C)	$\Delta I_{ON} / ^\circ\text{C}$	-1.5	mA / °C
	Junction Temperature	T_j	125	°C
Storage Temperature Range		T_{stg}	-55~125	°C
Operating Temperature Range		T_{opr}	-40~85	°C
Lead Soldering Temperature (10 s)		T_{sol}	260	°C
Isolation Voltage (AC, 1 min., R.H. $\leq$ 60%) (Note 2)		BV_S	1500	V_{rms}

(Note 1) : Two channels operating simultaneously.

(Note 2) : Device considered a two-terminal device : pins 1, 2, 3 and 4 shorted together and pins 5, 6, 7 and 8 shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{DD}	—	150	200	V
Forward Current	I_F	5	7.5	25	mA
On-State Current	I_{ON}	—	—	120	mA
Operating Temperature	T_{opr}	-20	—	65	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
DETECTOR	Off-State Current	I_{OFF}	$V_{OFF} = 200 \text{ V}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1 \text{ MHz}$	—	100	—	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I_{FT}	$I_{ON} = 150 \text{ mA}$	—	1	3	mA
On-State Resistance	R_{ON}	$I_{ON} = 150 \text{ mA}, I_F = 5 \text{ mA}$	—	5	8	Ω

ISOLATION CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	1500	—	—	V_{rms}
		AC, 1 second, in oil	—	3000	—	
		DC, 1 minute, in oil	—	3000	—	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time	t_{ON}	$R_L = 200 \Omega$ (Note 3) $V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$	—	0.6	1.5	ms
Turn-off Time	t_{OFF}		—	0.1	1.0	

(Note 3) : Switching Time Test Circuit

